NSN 5962-01-420-9604

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Bodv	l er	nath:
Dogv		IMUI.

Between 0.342 inches and 0.358 inches

Body Width:

Between 0.342 inches and 0.358 inches

Body Height:

Between 0.064 inches and 0.100 inches

Maximum Power Dissipation Rating:

0.5 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Pacer dawn

Features Provided:

Programmable and bipolar and monolithic and w/clock and electrostatic sensitive

Inclosure Configuration:

Leadless flat pack

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

14 input

Criticality Code Justification:

Cbbl

Case Outline Source And Designator:

C-2 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, programmed (pal 16r4a-2)

Voltage Rating And Type Per Characteristic:

7.0 volts power source

Time Rating Per Chacteristic:

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Pal

Special Features:

Altered item programmed using 14933 81036142 (which is 83149 m38510/81036) using programming instruction 7816354p173

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 leadless

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CI	~~	14	I i	ife:	
J.	16			HE.	

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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